



BCP5616T

80V NPN MEDIUM POWER TRANSISTOR IN SOT223

Features

- BV_{CEO} > 80V
- I_C = 1A High Continuous Collector Current
- I_{CM} = 2A Peak Pulse Current
- 2W Power Dissipation
- Low Saturation Voltage V_{CE(SAT)} <500mV @ 0.5A
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen- and Antimony-Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. https://www.diodes.com/quality/product-definitions/
- An Automotive-Compliant Part is Available Under Separate Datasheet (BCP5616TQ)

Applications

- Medium Power Switching or Amplification Applications
- AF Driver and Output Stages

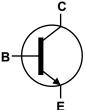
Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads.
 Solderable per MIL-STD-202, Method 208 @3)
- Weight: 0.112 grams (Approximate)

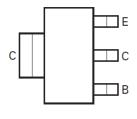
SOT223







Device Symbol



Top View Pin-Out

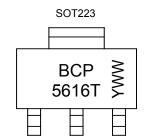
Ordering Information (Note 4)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
BCP5616TTA	Standard	BCP 5616T	7	12	1,000
BCP5616TTC	Standard	BCP 5616T	13	12	4,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



BCP 5616T = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 1 = 2021) WW or $\overline{W}W$ = Week Code (01~53)



Absolute Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Collector-Base Voltage	V _{CBO}	100	V	
Collector-Emitter Voltage	V _{CEO}	80	V	
Emitter-Base Voltage	V _{EBO}	5	V	
Continuous Collector Current	Ic	1	۸	
Peak Pulse Collector Current	I _{CM}	2	А	
Continuous Base Current	I _B	100	- mA	
Peak Pulse Base Current	I _{BM}	200		

Thermal Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 5)	P_{D}	2.5	W
Thermal Resistance, Junction to Ambient	(Note 5)	$R_{\theta JA}$	45.6	°C /W
Thermal Resistance, Junction to Leads (Note 6)		$R_{ heta JL}$	21.7	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C	

ESD Ratings (Note 7)

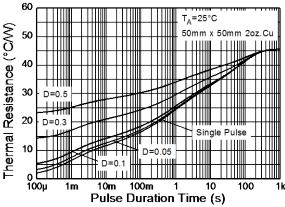
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge – Machine Model	ESD MM	400	V	С

^{5.} For a device mounted with the collector lead on 50mm x 50mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.

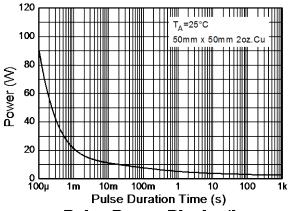
^{6.} Thermal resistance from junction to solder-point (at the end of the collector lead).
7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



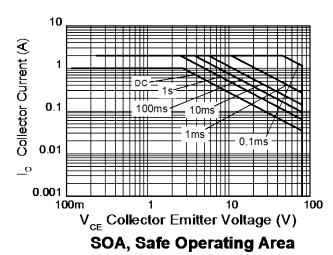
Thermal Characteristics and Derating Information

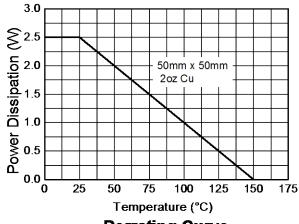


Transient Thermal Impedance



Pulse Power Dissipation





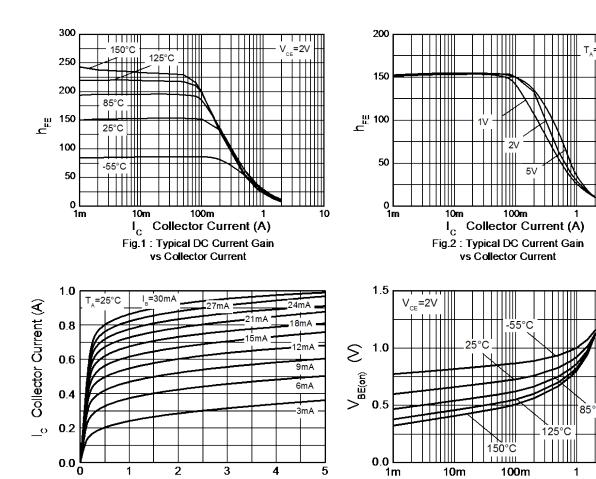


Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	100	-	-	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 8)	BV _{CEO}	80	_	-	V	I _C = 10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	7	-	ı	V	$I_{E} = 10 \mu A$
Collector Cut-Off Current	I _{CBO}	_	-	0.1 20	μΑ	V _{CB} = 30V V _{CB} = 30V, T _A = +150°C
Emitter Cut-Off Current	I _{EBO}	_	-	20	nA	V _{EB} = 6V
Static Forward Current Transfer Ratio (Note 8)	h _{FE}	63 100 40	-	250	-	I _C = 5mA, V _{CE} = 2V I _C = 150mA, V _{CE} = 2V I _C = 500mA, V _{CE} = 2V
Collector-Emitter Saturation Voltage (Note 8)	V _{CE(sat)}	_	1	0.5	>	I _C = 500mA, I _B = 50mA
Base-Emitter Turn-On Voltage (Note 8)	V _{BE(on)}	_	1	1.0	V	I _C = 500mA, V _{CE} = 2V
Transition Frequency	f⊤	100	150	1	MHz	I _C = 50mA, V _{CE} = 10V f = 100MHz
Output Capacitance	C_{obo}	_	_	25	pF	V _{CB} = 10V, f = 1MHz

Note:

Typical Electrical Characteristics (@ TA = +25°C, unless otherwise specified.)



 $\boldsymbol{V}_{\text{CE(sat)}}$ Fig.3: Typical Collector Current vs Collector-Emitter Saturation Voltage

3

(V)

2

I_C Collector Current (A) Fig.4: Typical Base-Emitter Turn-On Voltage vs Collector Current

100m

10m

1m

10

^{8.} Measured under pulsed conditions. Pulse width ≤ 300 µs. Duty cycle ≤ 2%.



Typical Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

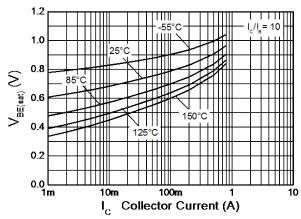


Fig 5: Typical Base-Emitter Saturation Voltage vs Collector Current

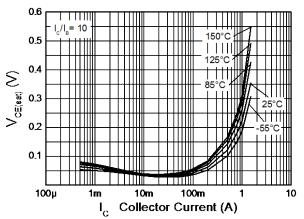


Fig 6: Typical Collector-Emitter Saturation Voltage vs Collector Current

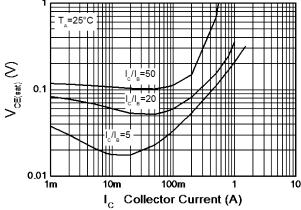


Fig 7: Typical Collector-Emitter Saturation Voltage vs Collector Current

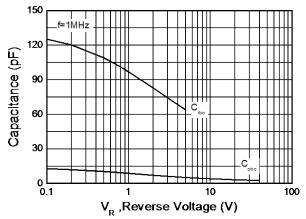
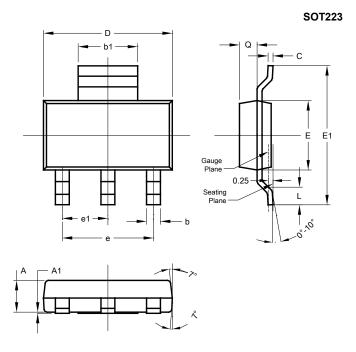


Fig 8: Typical Capacitance Characteristics



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

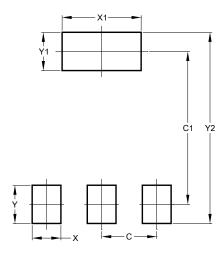


SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	_	_	4.60		
e1	_	_	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223



Dimensions	Value (in mm)
С	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00



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